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FDC2512

150V N-Channel PowerTrench® MOSFET

General Description

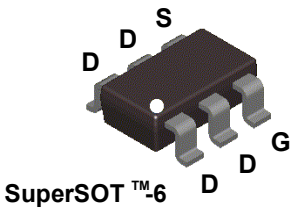
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

Applications

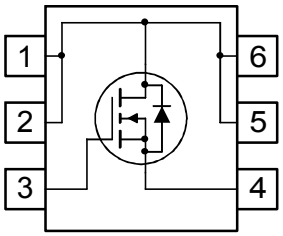
- DC/DC converter

Features

- 1.4 A, 150 V. $R_{DS(ON)}$ = 425 mΩ @ V_{GS} = 10 V
  $R_{DS(ON)}$ = 475 mΩ @ V_{GS} = 6 V
- High performance trench technology for extremely low $R_{DS(ON)}$
- Low gate charge (8nC typ)
- High power and current handling capability
- Fast switching speed



SuperSOT ™-6



Absolute Maximum Ratings

T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain-Source Voltage		150	V
V_{GSS}	Gate-Source Voltage		± 20	V
I_D	Drain Current – Continuous	(Note 1a)	1.4	A
	– Pulsed		8	
E_{AS}	Single Pulse Avalanche Energy	(Note 3)	13.5	mJ
P_D	Maximum Power Dissipation	(Note 1a)	1.6	W
		(Note 1b)	0.8	
T_J, T_{stg}	Operating and Storage Junction Temperature Range		–55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.252	FDC2512	7''	8mm	3000 units

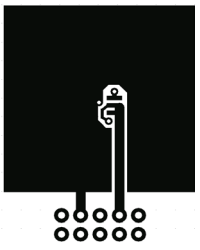
Electrical Characteristics

T_A = 25°C unless otherwise noted

Symbl	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	150			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		147		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 120 V, V_{GS} = 0 V			1	μA
I_{GSSF}	Gate–Body Leakage, Forward	V_{GS} = 20 V, V_{DS} = 0 V			100	nA
I_{GSSR}	Gate–Body Leakage, Reverse	V_{GS} = –20 V, V_{DS} = 0 V			–100	nA
On Characteristics (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	2	2.6	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		–5.6		mV/°C
$R_{DS(on)}$	Static Drain–Source On Resistance	V_{GS} = 10 V, I_D = 1.4 A V_{GS} = 6.0 V, I_D = 1.3 A V_{GS} = 10 V, I_D = 1.4 A, T_J = 125°C		319 332 624	425 475 875	mΩ
$I_{D(on)}$	On–State Drain Current	V_{GS} = 10 V, V_{DS} = 5 V	4			A
g_{FS}	Forward Transconductance	V_{DS} = 10 V, I_D = 1.4 A		4		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 75 V, V_{GS} = 0 V, f = 1.0 MHz		344		pF
C_{oss}	Output Capacitance			22		pF
C_{rss}	Reverse Transfer Capacitance			9		pF
R_g	Gate Resistance		0.1	1.4	3.0	Ω
Switching Characteristics (Note 2)						
$t_{d(on)}$	Turn–On Delay Time	V_{DD} = 75 V, I_D = 1 A, V_{GS} = 10 V, R_{GEN} = 6 Ω		6.5	13	ns
t_r	Turn–On Rise Time			3.5	7	ns
$t_{d(off)}$	Turn–Off Delay Time			22	33	ns
t_f	Turn–Off Fall Time			4	8	ns
Q_g	Total Gate Charge	V_{DS} = 75 V, I_D = 1.4 A, V_{GS} = 10 V		8	11	nC
Q_{gs}	Gate–Source Charge			1.5		nC
Q_{gd}	Gate–Drain Charge			2.3		nC
Drain–Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain–Source Diode Forward Current				1.3	A
V_{SD}	Drain–Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 1.3 A (Note 2)		0.8	1.2	V
t_{rr}	Diode Reverse Recovery Time	I_F = 1.4A, d_{iF}/d_t = 300 A/μs (Note 2)		45.8		nS
Q_{rr}	Diode Reverse Recovery Charge			119		nC

Notes:

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 78°C/W when mounted on a 1in^2 pad of 2 oz copper



b) 156°C/W when mounted on a minimum pad of 2 oz copper

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%

3. E_{AS} of 13.5 mJ is based on starting T_J = 25 °C; N-ch: L = 3 mH, I_{AS} = 3 A, V_{DD} = 150 V, V_{GS} = 10 V.

Typical Characteristics

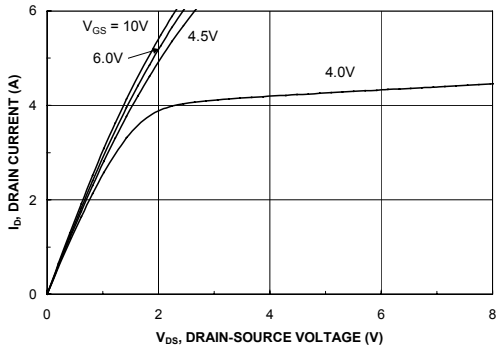


Figure 1. On-Region Characteristics.

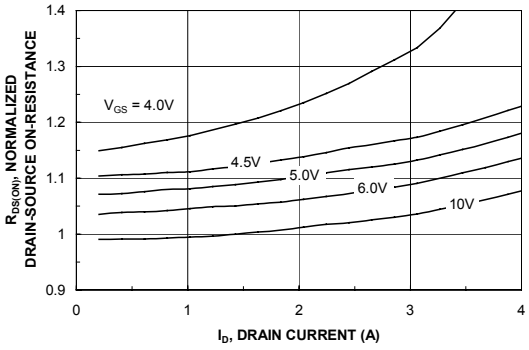


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

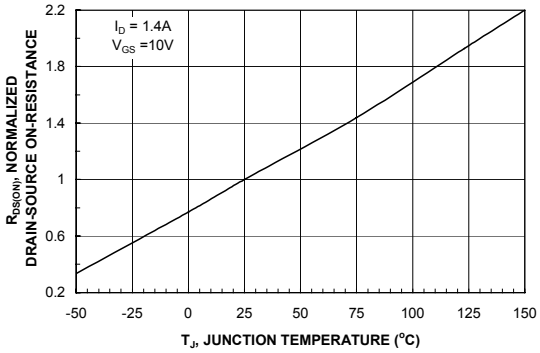


Figure 3. On-Resistance Variation with Temperature.

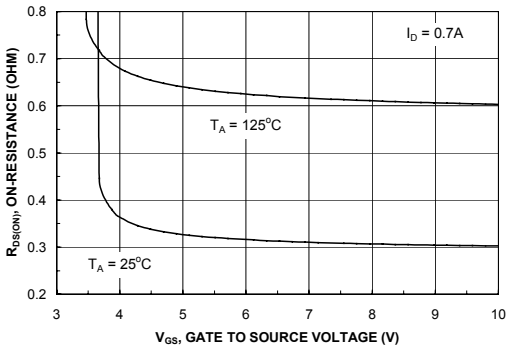


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

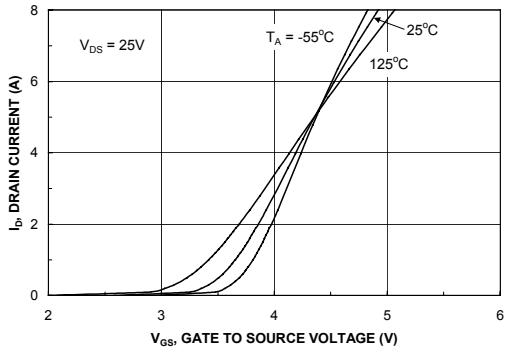


Figure 5. Transfer Characteristics.

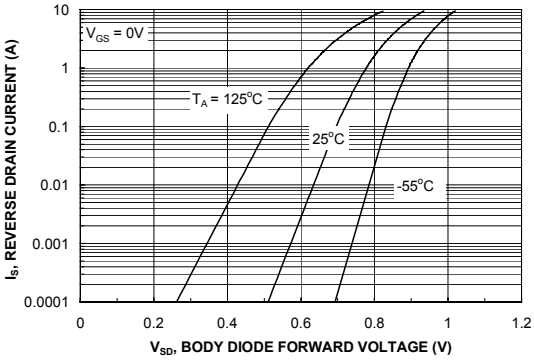


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics

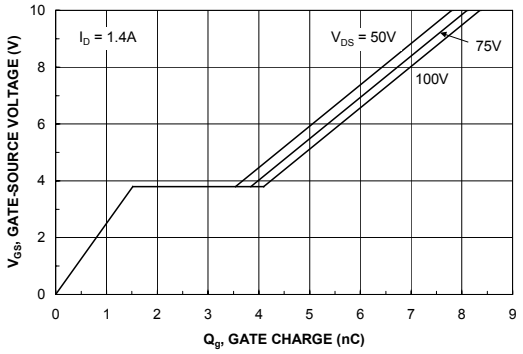


Figure 7. Gate Charge Characteristics.

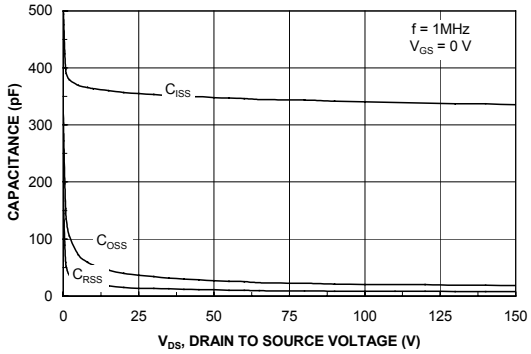


Figure 8. Capacitance Characteristics.

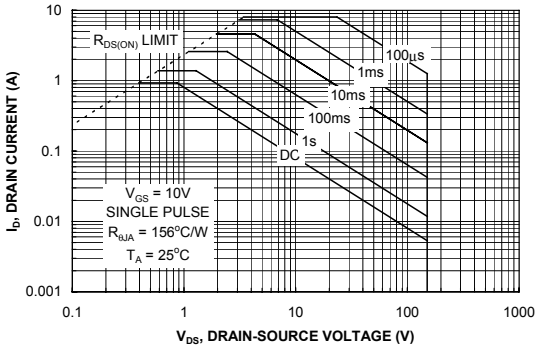


Figure 9. Maximum Safe Operating Area.

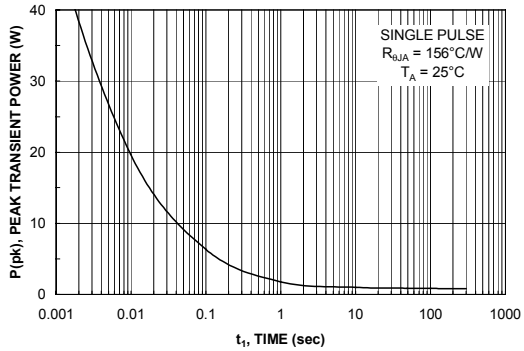


Figure 10. Single Pulse Maximum Power Dissipation.

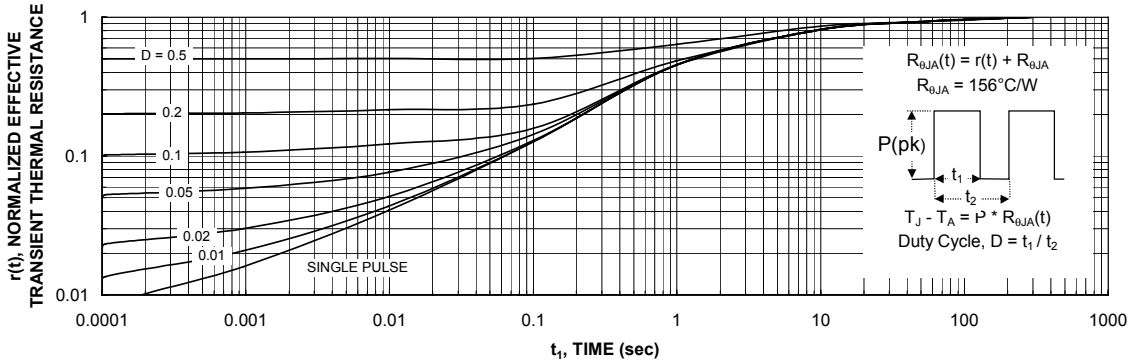
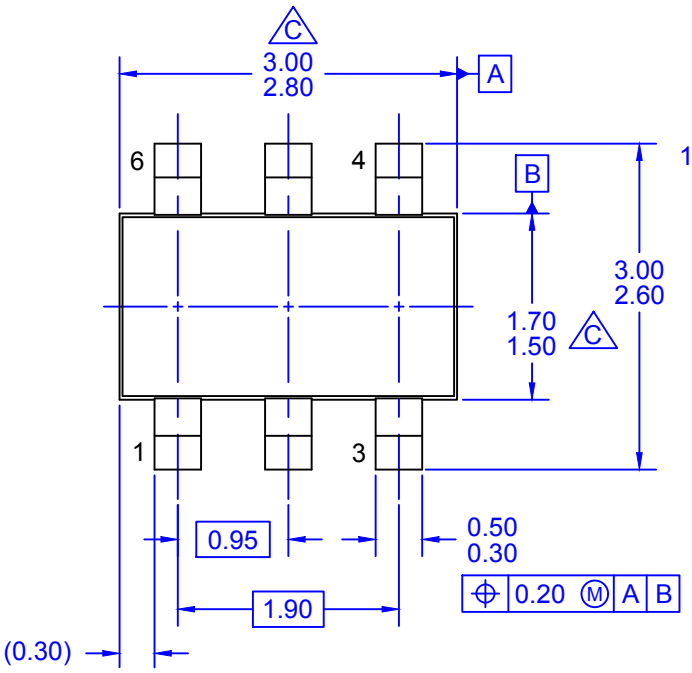
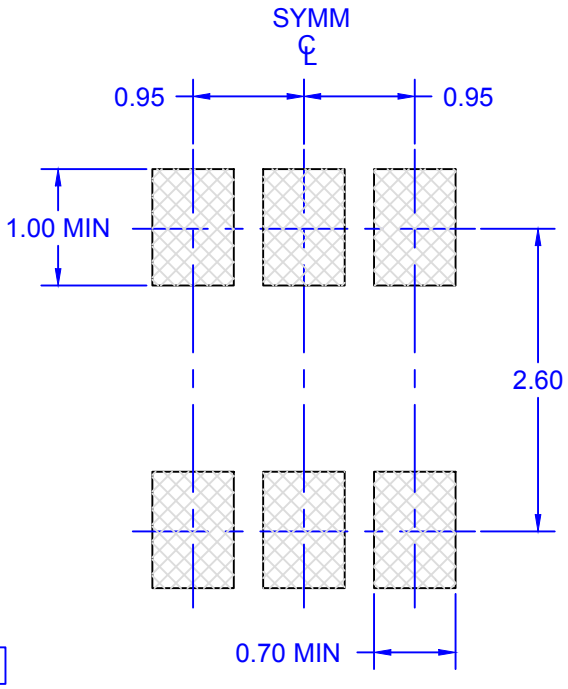


Figure 11. Transient Thermal Response Curve.

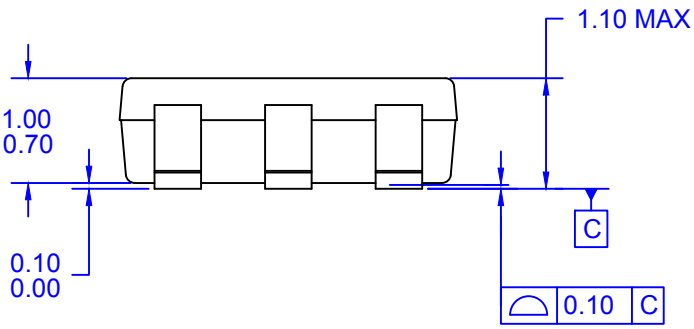
Thermal characterization performed using the conditions described in Note 1b.
Transient thermal response will change depending on the circuit board design.

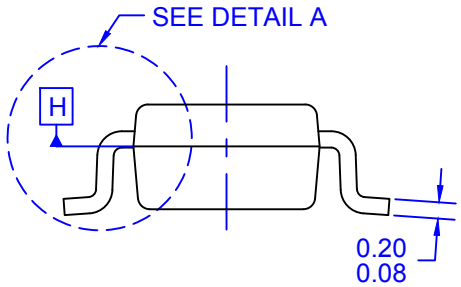
Dimensional Outline and Pad Layout

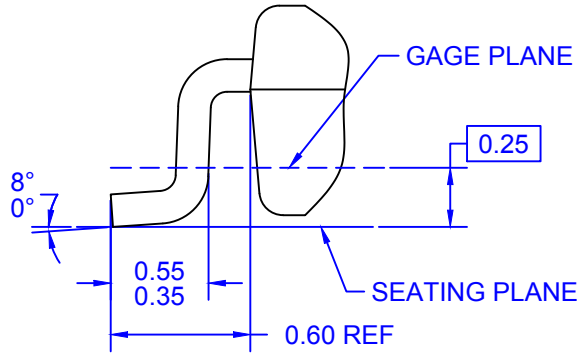




LAND PATTERN RECOMMENDATION







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